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View Online at https://aerobasegroup.com/nsn/5962-01-262-9878 **Body Length:** 0.540 inches **Body Width:** Between 0.245 inches and 0.300 inches **Body Height:** Between 0.045 inches and 0.100 inches **Maximum Power Dissipation Rating:** 2.0 watts **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **Features Provided:** Hermetically sealed and burn in and monolithic and bipolar and programmable **Inclosure Material:** Ceramic **Inclosure Configuration:** Flat pack **Output Logic Form:** Transistor-transistor logic **Input Circuit Pattern:** 12 input **Current Rating Per Characteristic:** 100.00 milliamperes forward current, peak total value not applicable **Terminal Surface Treatment:** Solder **Voltage Rating And Type Per Characteristic:** 12.0 volts power source **Time Rating Per Chacteristic:** 45.00 nanoseconds propagation delay time, low to high level output and 45.00 nanoseconds propagation delay time, high to low level output **Memory Device Type: Test Data Document:** 96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.). **Terminal Type And Quantity:** 20 flat leads Shelf Life: N/a

No

Unit Of Measure:

Demilitarization:

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